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What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Obsolete
Core Processor	F ² MC-8FX
Core Size	8-Bit
Speed	16MHz
Connectivity	I ² C, SIO, UART/USART
Peripherals	LCD, POR, PWM, WDT
Number of I/O	74
Program Memory Size	60KB (60K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	1.98K x 8
Voltage - Supply (Vcc/Vdd)	2.4V ~ 5.5V
Data Converters	A/D 8x8/10b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-LQFP
Supplier Device Package	80-LQFP (12x12)
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/mb95f418hpmc-g-sne2

Low-voltage detection reset circuit

Built-in low-voltage detector

Clock supervisor counter

Built-in clock supervisor counter function

Programmable port input voltage level

CMOS input level / hysteresis input level

Dual operation Flash memory

The program/erase operation and the read operation can be executed in different banks (upper bank/lower bank) simultaneously.

Flash memory security function

Protects the content of the Flash memory

4. Differences among Products and Notes on Product Selection

Current consumption

When using the on-chip debug function, take account of the current consumption of flash erase/write.

For details of current consumption, see “17. Electrical Characteristics”.

Package

For details of information on each package, see “3. Packages And Corresponding Products” and “21. Package Dimension”.

Operating voltage

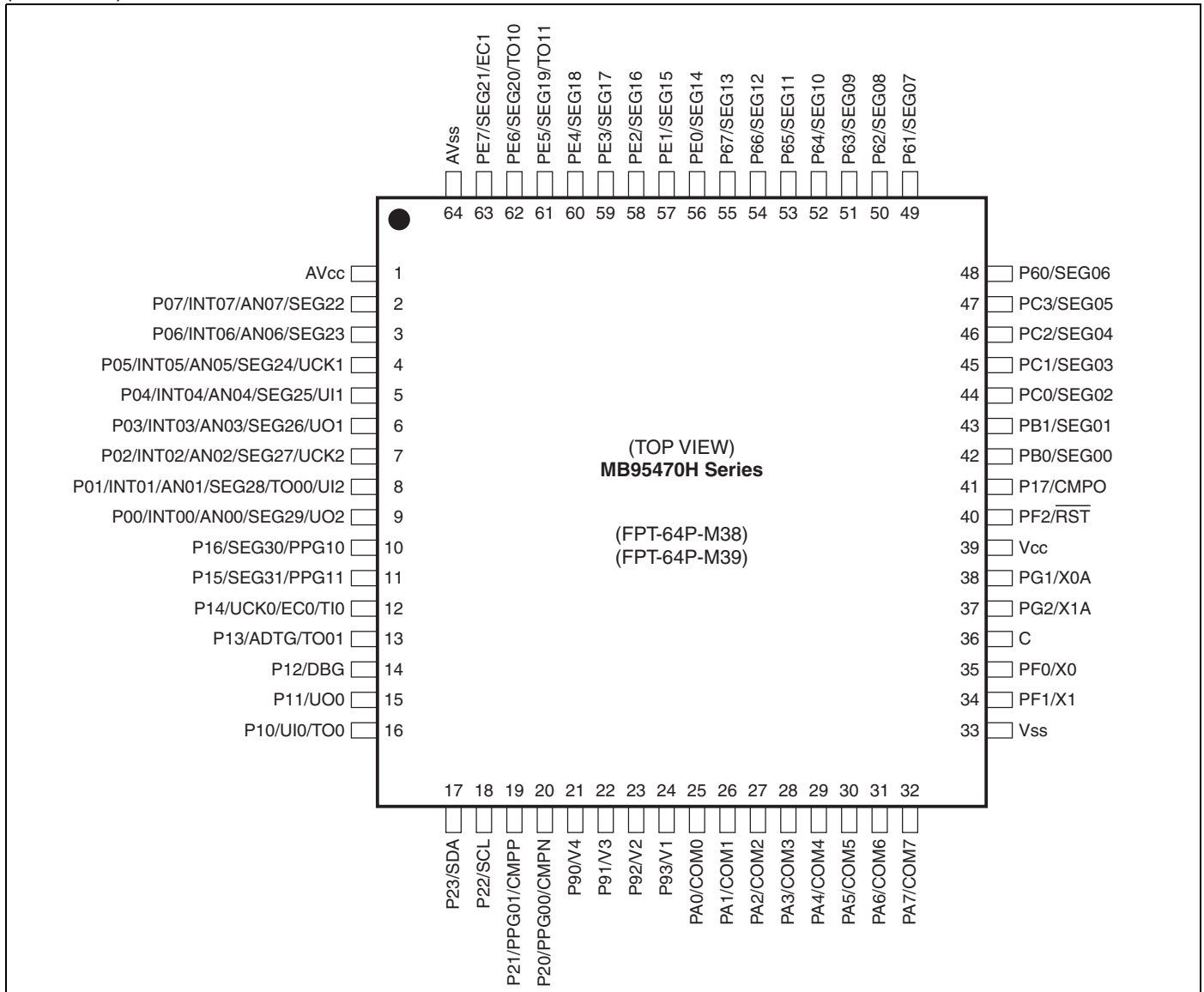
The operating voltage varies, depending on whether the on-chip debug function is used or not.

For details of the operating voltage, see “17. Electrical Characteristics”.

On-chip debug function

The on-chip debug function requires that V_{CC} , V_{SS} and 1 serial-wire be connected to an evaluation tool. For details of the connection method, refer to “Chapter 31 Example Of Serial Programming Connection” in the hardware manual of the MB95410H/470H Series.

(Continued)



Pin no.	Pin name	I/O circuit type*	Function
9	P00	W	General-purpose I/O port
	INT00		External interrupt input pin
	AN00		A/D analog input pin
	UO2		UART/SIO ch. 2 data output pin
10	P16	Y	General-purpose I/O port
	PPG10		8/16-bit PPG ch. 1 output pin
11	P15	Y	General-purpose I/O port
	PPG11		8/16-bit PPG ch. 1 output pin
12	P14	H	General-purpose I/O port
	UCK0		UART/SIO ch. 0 clock I/O pin
13	P13	H	General-purpose I/O port
	ADTG		A/D trigger input (ADTG) pin
14	P12	D	General-purpose I/O port
	DBG		DBG input pin
15	P11	H	General-purpose I/O port
	UO0		UART/SIO ch. 0 data output pin
16	P10	G	General-purpose I/O port
	UI0		UART/SIO ch. 0 data input pin
17	P53	H	General-purpose I/O port
	TO0		16-bit reload timer output pin
18	P52	H	General-purpose I/O port
	TI0		16-bit reload timer input pin
	TO00		8/16-bit composite timer ch. 0 output pin
19	P51	H	General-purpose I/O port
	EC0		8/16-bit composite timer ch. 0 clock input pin
20	P50	H	General-purpose I/O port
	TO01		8/16-bit composite timer ch. 0 output pin
21	P23	I	General-purpose I/O port
	SDA		I ² C data I/O pin
22	P22	I	General-purpose I/O port
	SCL		I ² C clock I/O pin
23	P21	T	General-purpose I/O port
	PPG01		8/16-bit PPG ch. 0 output pin
	CMPP		Voltage comparator input pin
24	P20	T	General-purpose I/O port
	PPG00		8/16-bit PPG ch. 0 output pin
	CMPN		Voltage comparator input pin

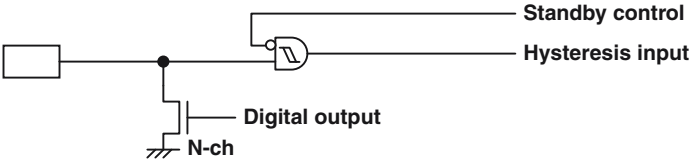
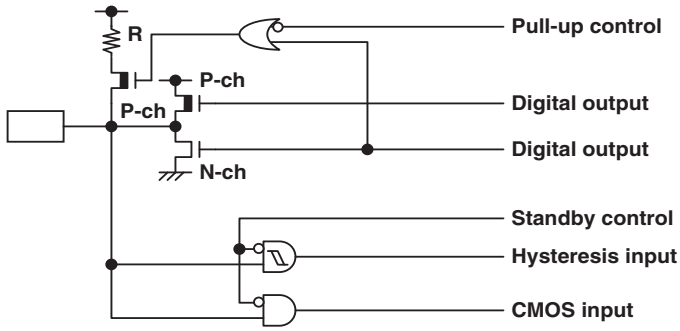
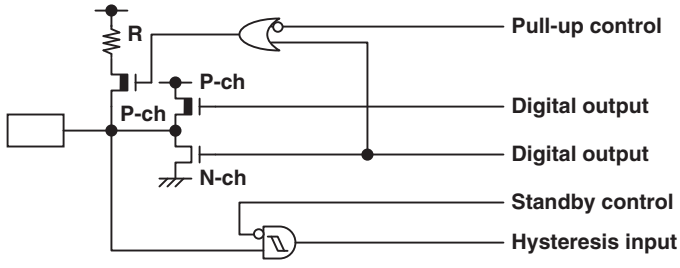
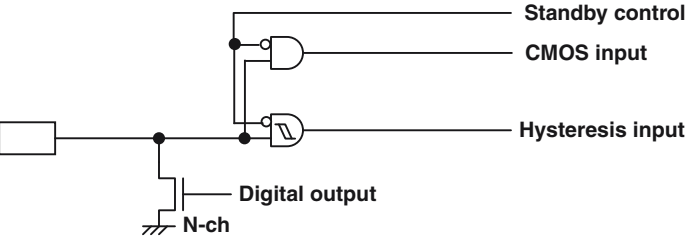
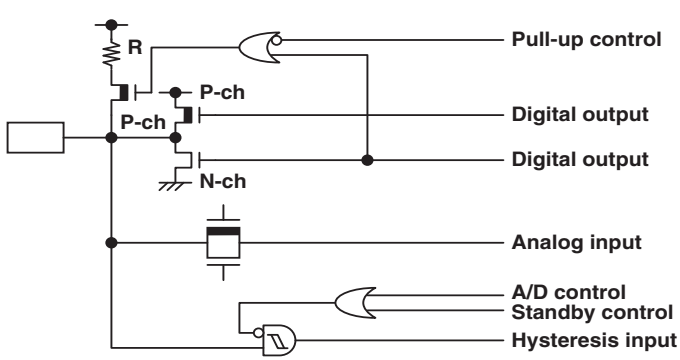
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Pin no.	Pin name	I/O circuit type*	Function
44	C	—	Capacitor connection pin
45	PG2	C	General-purpose I/O port
	X1A		Subclock oscillation pin (32 kHz)
46	PG1	C	General-purpose I/O port
	X0A		Subclock oscillation pin (32 kHz)
47	V _{CC}	—	Power supply pin
48	PF2	A	General-purpose I/O port
	RST		Reset pin Dedicate reset pin for MB95F414H/F416H/F418H
49	P17	H	General-purpose I/O port
	CMPO		Voltage comparator output pin
50	PB0	M	General-purpose I/O port
	SEG00		LCDC SEG output pin
51	PB1	M	General-purpose I/O port
	SEG01		LCDC SEG output pin
52	PC0	M	General-purpose I/O port
	SEG02		LCDC SEG output pin
53	PC1	M	General-purpose I/O port
	SEG03		LCDC SEG output pin
54	PC2	M	General-purpose I/O port
	SEG04		LCDC SEG output pin
55	PC3	M	General-purpose I/O port
	SEG05		LCDC SEG output pin
56	PC4	M	General-purpose I/O port
	SEG06		LCDC SEG output pin
57	PC5	M	General-purpose I/O port
	SEG07		LCDC SEG output pin
58	PC6	M	General-purpose I/O port
	SEG08		LCDC SEG output pin
59	PC7	M	General-purpose I/O port
	SEG09		LCDC SEG output pin
60	P60	M	General-purpose I/O port
	SEG10		LCDC SEG output pin
61	P61	M	General-purpose I/O port
	SEG11		LCDC SEG output pin
62	P62	M	General-purpose I/O port
	SEG12		LCDC SEG output pin

(Continued)

Pin no.	Pin name	I/O circuit type*	Function
41	P17	H	General-purpose I/O port
	CMPO		Voltage comparator output pin
42	PB0	M	General-purpose I/O port
	SEG00		LCDC SEG output pin
43	PB1	M	General-purpose I/O port
	SEG01		LCDC SEG output pin
44	PC0	M	General-purpose I/O port
	SEG02		LCDC SEG output pin
45	PC1	M	General-purpose I/O port
	SEG03		LCDC SEG output pin
46	PC2	M	General-purpose I/O port
	SEG04		LCDC SEG output pin
47	PC3	M	General-purpose I/O port
	SEG05		LCDC SEG output pin
48	P60	M	General-purpose I/O port
	SEG06		LCDC SEG output pin
49	P61	M	General-purpose I/O port
	SEG07		LCDC SEG output pin
50	P62	M	General-purpose I/O port
	SEG08		LCDC SEG output pin
51	P63	M	General-purpose I/O port
	SEG09		LCDC SEG output pin
52	P64	M	General-purpose I/O port
	SEG10		LCDC SEG output pin
53	P65	M	General-purpose I/O port
	SEG11		LCDC SEG output pin
54	P66	M	General-purpose I/O port
	SEG12		LCDC SEG output pin
55	P67	M	General-purpose I/O port
	SEG13		LCDC SEG output pin
56	PE0	M	General-purpose I/O port
	SEG14		LCDC SEG output pin
57	PE1	M	General-purpose I/O port
	SEG15		LCDC SEG output pin

(Continued)

Type	Circuit	Remarks
D	 <p>Standby control</p> <p>Hysteresis input</p> <p>Digital output</p> <p>N-ch</p>	<ul style="list-style-type: none"> • N-ch open drain output • Hysteresis input
G	 <p>Pull-up control</p> <p>Digital output</p> <p>Digital output</p> <p>Standby control</p> <p>Hysteresis input</p> <p>CMOS input</p> <p>P-ch</p> <p>P-ch</p> <p>N-ch</p> <p>R</p>	<ul style="list-style-type: none"> • CMOS output • Hysteresis input • CMOS input • Pull-up control available
H	 <p>Pull-up control</p> <p>Digital output</p> <p>Digital output</p> <p>Standby control</p> <p>Hysteresis input</p> <p>P-ch</p> <p>P-ch</p> <p>N-ch</p> <p>R</p>	<ul style="list-style-type: none"> • CMOS output • Hysteresis input • Pull-up control available
I	 <p>Standby control</p> <p>CMOS input</p> <p>Hysteresis input</p> <p>Digital output</p> <p>N-ch</p>	<ul style="list-style-type: none"> • N-ch open drain output • CMOS input • Hysteresis input
J	 <p>Pull-up control</p> <p>Digital output</p> <p>Digital output</p> <p>Analog input</p> <p>A/D control</p> <p>Standby control</p> <p>Hysteresis input</p> <p>P-ch</p> <p>P-ch</p> <p>N-ch</p> <p>R</p>	<ul style="list-style-type: none"> • CMOS output • Hysteresis input • Analog input • Pull-up control available

(Continued)

9. Notes on Device Handling

Preventing latch-ups

When using the device, ensure that the voltage applied does not exceed the maximum voltage rating.

In a CMOS IC, if a voltage higher than V_{CC} or a voltage lower than V_{SS} is applied to an input/output pin that is neither a medium-withstand voltage pin nor a high-withstand voltage pin, or if a voltage out of the rating range of power supply voltage mentioned in "17.1 Absolute Maximum Ratings" of "17. Electrical Characteristics" is applied to the V_{CC} pin or the V_{SS} pin, a latch-up may occur.

When a latch-up occurs, power supply current increases significantly, which may cause a component to be thermally destroyed.

Stabilizing supply voltage

Supply voltage must be stabilized.

A malfunction may occur when power supply voltage fluctuates rapidly even though the fluctuation is within the guaranteed operating range of the V_{CC} power supply voltage.

As a rule of voltage stabilization, suppress voltage fluctuation so that the fluctuation in V_{CC} ripple (p-p value) at the commercial frequency (50 Hz/60 Hz) does not exceed 10% of the standard V_{CC} value, and the transient fluctuation rate does not exceed 0.1 V/ms at a momentary fluctuation such as switching the power supply.

Notes on using the external clock

When an external clock is used, oscillation stabilization wait time is required for power-on reset, wake-up from subclock mode or stop mode.

10. Pin Connection

Treatment of unused input pins

If an unused input pin is left unconnected, a component may be permanently damaged due to malfunctions or latch-ups. Always pull up or pull down an unused input pin through a resistor of at least 2 k Ω . Set an unused input/output pin to the output state and leave it unconnected, or set it to the input state and treat it the same as an unused input pin. If there is an unused output pin, leave it unconnected.

Power supply pins

To reduce unnecessary electro-magnetic emission, prevent malfunctions of strobe signals due to an increase in the ground level, and conform to the total output current standard, always connect the V_{CC} pin and the V_{SS} pin to the power supply and ground outside the device. In addition, connect the current supply source to the V_{CC} pin and the V_{SS} pin with low impedance.

It is also advisable to connect a ceramic capacitor of approximately 0.1 μ F as a bypass capacitor between the V_{CC} pin and the V_{SS} pin at a location close to this device.

DBG pin

Connect the DBG pin directly to an external pull-up resistor.

To prevent the device from unintentionally entering the debug mode due to noise, minimize the distance between the DBG pin and the V_{CC} or V_{SS} pin when designing the layout of the printed circuit board.

The DBG pin should not stay at "L" level after power-on until the reset output is released.

\overline{RST} pin

Connect the \overline{RST} pin directly to an external pull-up resistor.

To prevent the device from unintentionally entering the reset mode due to noise, minimize the distance between the \overline{RST} pin and the V_{CC} or V_{SS} pin when designing the layout of the printed circuit board.

The PF2/ \overline{RST} pin functions as the reset input/output pin after power-on. In addition, the reset output function of the PF2/ \overline{RST} pin can be enabled by the RSTOE bit in the SYSC register, and the reset input function or the general purpose I/O function can be selected by the RSTEN bit in the SYSC register.

Analog power supply

Always set the same potential to AV_{CC} and V_{CC} pins. When V_{CC} is larger than AV_{CC} , the current may flow through the AN00 to AN07 pins.

14. I/O Map (MB95410H Series)

Address	Register abbreviation	Register name	R/W	Initial value
0000 _H	PDR0	Port 0 data register	R/W	00000000 _B
0001 _H	DDR0	Port 0 direction register	R/W	00000000 _B
0002 _H	PDR1	Port 1 data register	R/W	00000000 _B
0003 _H	DDR1	Port 1 direction register	R/W	00000000 _B
0004 _H	—	(Disabled)	—	—
0005 _H	WATR	Oscillation stabilization wait time setting register	R/W	11111111 _B
0006 _H	PLLC	PLL control register	R/W	00000000 _B
0007 _H	SYCC	System clock control register	R/W	XXXXXX11 _B
0008 _H	STBC	Standby control register	R/W	0000XXXX _B
0009 _H	RSRR	Reset source register	R/W	000XXXXX _B
000A _H	TBTC	Time-base timer control register	R/W	00000000 _B
000B _H	WPCR	Watch prescaler control register	R/W	00000000 _B
000C _H	WDTC	Watchdog timer control register	R/W	00000000 _B
000D _H	SYCC2	System clock control register 2	R/W	XX100011 _B
000E _H	PDR2	Port 2 data register	R/W	00000000 _B
000F _H	DDR2	Port 2 direction register	R/W	00000000 _B
0010 _H , 0011 _H	—	(Disabled)	—	—
0012 _H	PDR4	Port 4 data register	R/W	00000000 _B
0013 _H	DDR4	Port 4 direction register	R/W	00000000 _B
0014 _H	PDR5	Port 5 data register	R/W	00000000 _B
0015 _H	DDR5	Port 5 direction register	R/W	00000000 _B
0016 _H	PDR6	Port 6 data register	R/W	00000000 _B
0017 _H	DDR6	Port 6 direction register	R/W	00000000 _B
0018 _H to 001B _H	—	(Disabled)	—	—
001C _H	PDR9	Port 9 data register	R/W	00000000 _B
001D _H	DDR9	Port 9 direction register	R/W	00000000 _B
001E _H	PDRA	Port A data register	R/W	00000000 _B
001F _H	DDRA	Port A direction register	R/W	00000000 _B
0020 _H	PDRB	Port B data register	R/W	00000000 _B
0021 _H	DDRB	Port B direction register	R/W	00000000 _B
0022 _H	PDRC	Port C data register	R/W	00000000 _B
0023 _H	DDRC	Port C direction register	R/W	00000000 _B
0024 _H , 0025 _H	—	(Disabled)	—	—

(Continued)

17. Electrical Characteristics

17.1 Absolute Maximum Ratings

Parameter	Symbol	Rating		Unit	Remarks
		Min	Max		
Power supply voltage* ¹	V_{CC}	$V_{SS} - 0.3$	$V_{SS} + 6$	V	
Input voltage* ¹	V_I	$V_{SS} - 0.3$	$V_{SS} + 6$	V	* ²
Output voltage* ¹	V_O	$V_{SS} - 0.3$	$V_{SS} + 6$	V	* ²
Maximum clamp current	I_{CLAMP}	-2	+2	mA	Applicable to specific pins* ³
Total maximum clamp current	$\Sigma I_{CLAMP} $	—	20	mA	Applicable to specific pins* ³
"L" level maximum output current	I_{CL}	—	15	mA	
"L" level average current	I_{CLAV}	—	4	mA	Average output current = operating current × operating ratio (1 pin)
"L" level total maximum output current	ΣI_{OL}	—	100	mA	
"L" level total average output current	ΣI_{OLAV}	—	50	mA	Total average output current = operating current × operating ratio (Total number of pins)
"H" level maximum output current	I_{CH}	—	-15	mA	
"H" level average current	I_{CHAV}	—	-4	mA	Average output current = operating current × operating ratio (1 pin)
"H" level total maximum output current	ΣI_{OH}	—	-100	mA	
"H" level total average output current	ΣI_{OHAV}	—	-50	mA	Total average output current = operating current × operating ratio (Total number of pins)
Power consumption	P_d	—	320	mW	
Operating temperature	T_A	-40	+85	°C	
Storage temperature	T_{stg}	-55	+150	°C	

*1: These parameters are based on the condition that $V_{SS} = 0.0$ V.

*2: V_I and V_O must not exceed $V_{CC} + 0.3$ V. V_I must not exceed the rated voltage. However, if the maximum current to/from an input is limited by means of an external component, the I_{CLAMP} rating is used instead of the V_I rating.

(Continued)

$(V_{CC} = 5.0 \text{ V} \pm 10\%, V_{SS} = 0.0 \text{ V}, T_A = -40^\circ\text{C to } +85^\circ\text{C})$

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ ^{*4}	Max		
Power supply current ^{*3}	I_{CCMPLL}	V_{CC} (External clock operation)	$V_{CC} = 5.5 \text{ V}$ $F_{CH} = 4 \text{ MHz}$ $F_{MP} = 10 \text{ MHz}$ Main PLL mode (multiplied by 2.5) $T_A = +25^\circ\text{C}$	—	9.7	12.5	mA	
			$V_{CC} = 5.5 \text{ V}$ $F_{CH} = 6.44 \text{ MHz}$ $F_{MP} = 16 \text{ MHz}$ Main PLL mode (multiplied by 2.5) $T_A = +25^\circ\text{C}$	—	13.9	20	mA	
	I_{CCMCR}	V_{CC}	$V_{CC} = 5.5 \text{ V}$ $F_{CRH} = 12.5 \text{ MHz}$ $F_{MP} = 12.5 \text{ MHz}$ Main CR clock mode	—	11	13.2	mA	
	I_{CCSCR}		$V_{CC} = 5.5 \text{ V}$ Sub-CR clock mode (multiplied by 2.5) $T_A = +25^\circ\text{C}$	—	112	410	μA	
	I_{CCTS}	V_{CC} (External clock operation)	$V_{CC} = 5.5 \text{ V}$ $F_{CH} = 32 \text{ MHz}$ Time-base timer mode $T_A = +25^\circ\text{C}$	—	1	3	mA	
	I_{CCH}		$V_{CC} = 5.5 \text{ V}$ Substop mode $T_A = +25^\circ\text{C}$	—	3.1	22.5	μA	Main stop mode with one clock selected
	I_A	AV_{CC}	Current consumption for A/D conversion at 16 MHz	—	1.5	4.7	mA	
	I_{AH}		Current consumption for stopping A/D conversion at 16 MHz	—	1	5	μA	
	I_V		Current consumption of voltage comparator at 16 MHz	—	113	350	μA	

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($V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0.0 \text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Condition	Value			Unit	Remarks
				Min	Typ ^{*4}	Max		
Power supply current ^{*3}	I_{LVD}	V_{CC}	Current consumption of the low-voltage detection circuit	—	31	54	μA	
	I_{CRH}		Current consumption of the main CR oscillator	—	0.5	0.6	mA	
	I_{CRL}		Current consumption of the sub-CR oscillator oscillating at 100 kHz	—	20	72	μA	
LCD internal division resistance	R_{LCD}	—	Between V4 and V_{SS}	—	400	—	$k\Omega$	
				—	40	—	$k\Omega$	
COM0 to COM7 output impedance	R_{VCOM}	COM0 to COM7	V1 to V4 = 4.1 V	—	—	5	$k\Omega$	
SEG00 to SEG39 output impedance	R_{VSEG}	SEG00 to SEG39		—	—	7	$k\Omega$	
LCD leakage current	I_{LCDL}	V0 to V4, COM0 to COM7, SEG00 to SEG39	—	-1	—	+1	μA	

*1: The input levels of P01, P04, P10, P22 and P23 can be switched between “CMOS input level” and “hysteresis input level”. The input level selection register (ILSR) is used to switch between the two input levels.

*2: P40 to P43, P50 to P53, P94, PB2 to PB4 and PC4 to PC7 are only available on the MB95410H Series.

*3: • The power supply current is determined by the external clock. When the low-voltage detection option is selected, the power-supply current will be the sum of adding the current consumption of the low-voltage detection circuit (I_{LVD}) to one of the value from I_{CC} to I_{CCH} . In addition, when both the low-voltage detection option and the CR oscillator are selected, the power supply current will be the sum of adding up the current consumption of the low-voltage detection circuit, the current consumption of the CR oscillators (I_{CRH} , I_{CRL}) and a specified value. In on-chip debug mode, the CR oscillator (I_{CRH}) and the low-voltage detection circuit are always enabled, and current consumption therefore increases accordingly.

• See “17.4. AC Characteristics: 17.4.1. Clock Timing” for F_{CH} and F_{CL} .

• See “17.4. AC Characteristics: 17.4.2. Source Clock/Machine Clock” for F_{MP} and F_{MPL} .

*4: $V_{CC} = 5.0 \text{ V}$, $T_A = +25^\circ\text{C}$

Input waveform generated when an external clock (main clock) is used

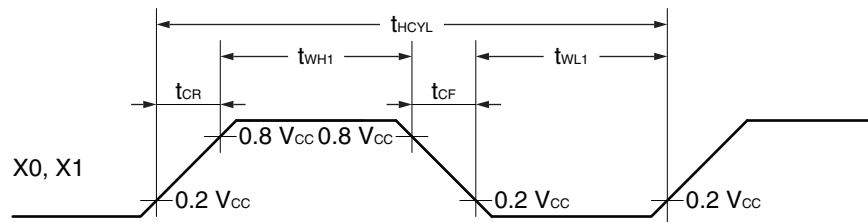
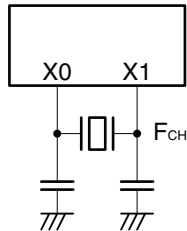
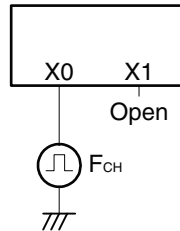


Figure of main clock input port external connection

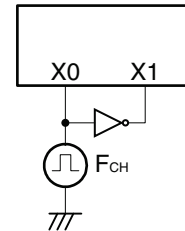
When a crystal oscillator or a ceramic oscillator is used



When the external clock is used (X1 is open)



When the external clock is used



Input waveform generated when an external clock (subclock) is used

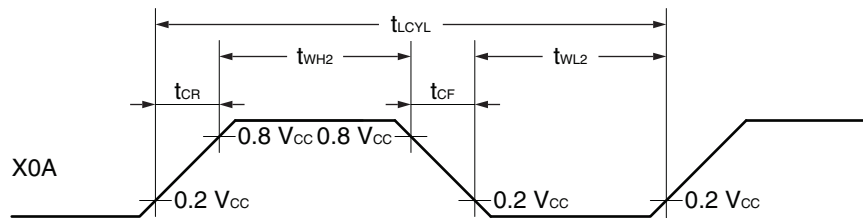
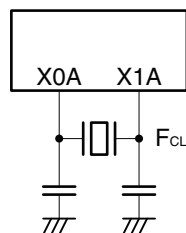
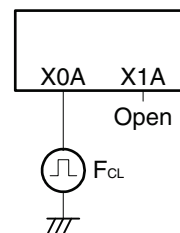


Figure of subclock input port external connection

When a crystal oscillator or a ceramic oscillator is used



When the external clock is used



17.4.2 Source Clock/Machine Clock

($V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0.0 \text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Pin name	Value			Unit	Remarks
			Min	Typ	Max		
Source clock cycle time* ¹	t _{SCLK}	—	61.5	—	2000	ns	When the main oscillation clock is used Min: F _{CH} = 32.5 MHz, divided by 2 Max: F _{CH} = 1 MHz, divided by 2
			61.5	—	2000	ns	When the main oscillation clock is used Min: F _{CH} = 8.125 MHz, multiplied by the PLL multiplier of 2 Max: F _{CH} = 1 MHz, divided by 2
			80	—	1000	ns	When the main CR clock is used Min: F _{CRH} = 12.5 MHz Max: F _{CRH} = 1 MHz
			—	61	—	μs	When the sub-oscillation clock is used F _{CL} = 32.768 kHz, divided by 2
			—	20	—	μs	When the sub-CR clock is used F _{CRL} = 100 kHz, divided by 2
Source clock frequency	F _{SP}	—	0.50	—	16.25	MHz	When the main oscillation clock is used
			1	—	12.5	MHz	When the main CR clock is used
	F _{SPL}		—	16.384	—	kHz	When the sub-oscillation clock is used
			—	50	—	kHz	When the sub-CR clock is used F _{CRL} = 100 kHz, divided by 2
Machine clock cycle time* ² (minimum instruction execution time)	t _{MCLK}	—	61.5	—	32000	ns	When the main oscillation clock is used Min: F _{SP} = 16.25 MHz, no division Max: F _{SP} = 0.5 MHz, divided by 16
			80	—	16000	ns	When the main CR clock is used Min: F _{SP} = 12.5 MHz Max: F _{SP} = 1 MHz, divided by 16
			61	—	976.5	μs	When the sub-oscillation clock is used Min: F _{SPL} = 16.384 kHz, no division Max: F _{SPL} = 16.384 kHz, divided by 16
			20	—	320	μs	When the sub-CR clock is used Min: F _{SPL} = 50 kHz, no division Max: F _{SPL} = 50 kHz, divided by 16
Machine clock frequency	F _{MP}	—	0.031	—	16.25	MHz	When the main oscillation clock is used
			0.0625	—	12.5	MHz	When the main CR clock is used
	F _{MPL}		1.024	—	16.384	kHz	When the sub-oscillation clock is used
			3.125	—	50	kHz	When the sub-CR clock is used F _{CRL} = 100 kHz

*1: This is the clock before it is divided according to the division ratio set by the machine clock divide ratio select bits (SYCC:DIV1, DIV0). This source clock is divided to become a machine clock according to the division ratio set by the machine clock divide ratio select bits (SYCC:DIV1, DIV0). In addition, a source clock can be selected from the following.

- Main clock divided by 2
- PLL multiplication of main clock (select from 2, 2.5, 4 multiplication)
- Main CR clock divided by 2
- Subclock divided by 2
- Sub-CR clock divided by 2

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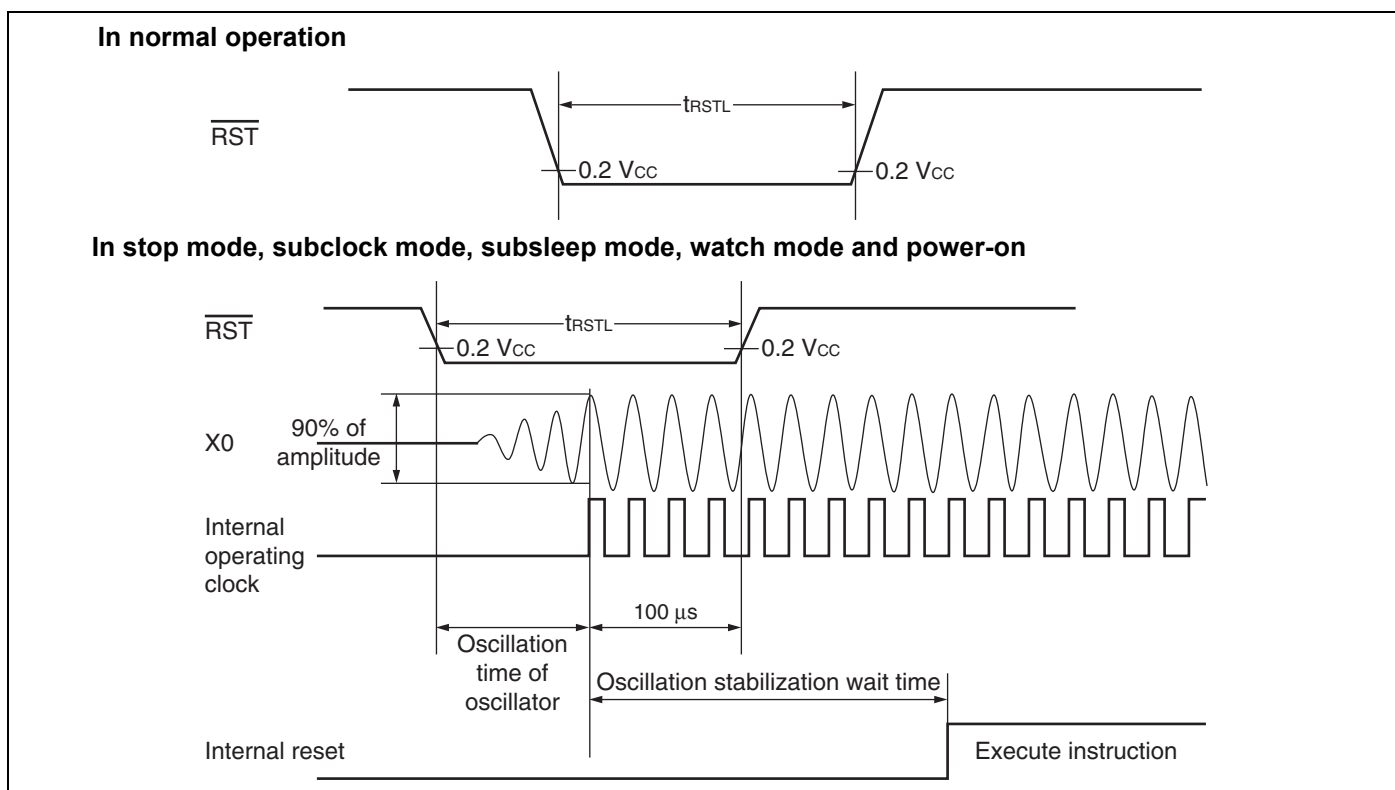
17.4.3 External Reset

($V_{CC} = 5.0 \text{ V} \pm 10\%$, $V_{SS} = 0.0 \text{ V}$, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$)

Parameter	Symbol	Value		Unit	Remarks
		Min	Max		
$\overline{\text{RST}}$ "L" level pulse width	t_{RSTL}	$2 t_{\text{MCLK}}^{*1}$	—	ns	In normal operation
		Oscillation time of the oscillator ^{*2} + 100	—	μs	In stop mode, subclock mode, subsleep mode, watch mode, and power-on
		100	—	μs	In time-base timer mode

*1: See "17.4.2. Source Clock/Machine Clock" for t_{MCLK} .

*2: The oscillation time of an oscillator is the time for it to reach 90% of its amplitude. The crystal oscillator has an oscillation time of between several ms and tens of ms. The ceramic oscillator has an oscillation time of between hundreds of μs and several ms. The external clock has an oscillation time of 0 ms. The CR oscillator clock has an oscillation time of between several μs and several ms.



17.4.8 I²C Timing

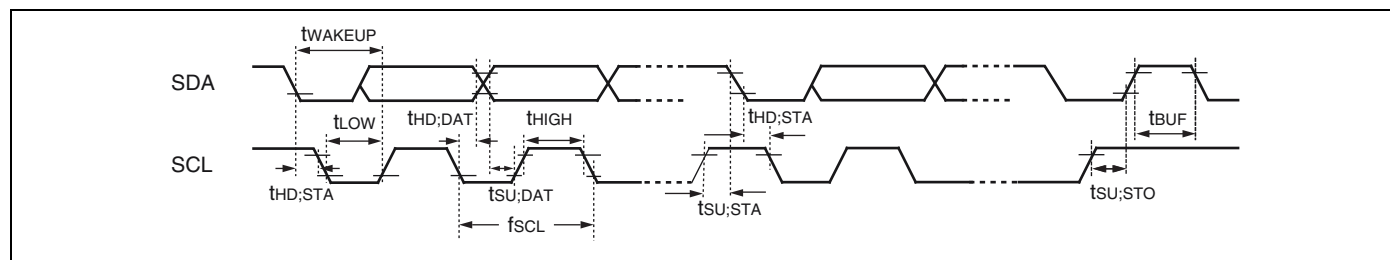
(V_{CC} = 5.0 V ±10%, AV_{SS} = V_{SS} = 0.0 V, T_A = -40°C to +85°C)

Parameter	Symbol	Pin name	Conditions	Value				Unit
				Standard-mode		Fast-mode		
				Min	Max	Min	Max	
SCL clock frequency	f _{SCL}	SCL	R = 1.7 kΩ, C = 50 pF*1	0	100	0	400	kHz
(Repeat) Start condition hold time SDA ↓ → SCL ↓	t _{HD;STA}	SCL, SDA		4.0	—	0.6	—	μs
SCL clock “L” width	t _{LOW}	SCL		4.7	—	1.3	—	μs
SCL clock “H” width	t _{HIGH}	SCL		4.0	—	0.6	—	μs
(Repeat) Start condition setup time SCL ↑ → SDA ↓	t _{SU;STA}	SCL, SDA		4.7	—	0.6	—	μs
Data hold time SCL ↓ → SDA ↓ ↑	t _{HD;DAT}	SCL, SDA		0	3.45*2	0	0.9*3	μs
Data setup time SDA ↓ ↑ → SCL ↑	t _{SU;DAT}	SCL, SDA		0.25	—	0.1	—	μs
Stop condition setup time SCL ↑ → SDA ↑	t _{SU;STO}	SCL, SDA		4.0	—	0.6	—	μs
Bus free time between stop condition and start condition	t _{BUF}	SCL, SDA		4.7	—	1.3	—	μs

*1: R represents the pull-up resistor of the SCL and SDA lines, and C the load capacitor of the SCL and SDA lines.

*2: The maximum t_{HD;DAT} in the Standard-mode is applicable only when the time during which the device is holding the SCL signal at "L" (t_{LOW}) does not extend.

*3: A Fast-mode I²C-bus device can be used in a Standard-mode I²C-bus system, provided that the condition of t_{SU;DAT} ≥ 250 ns is fulfilled.



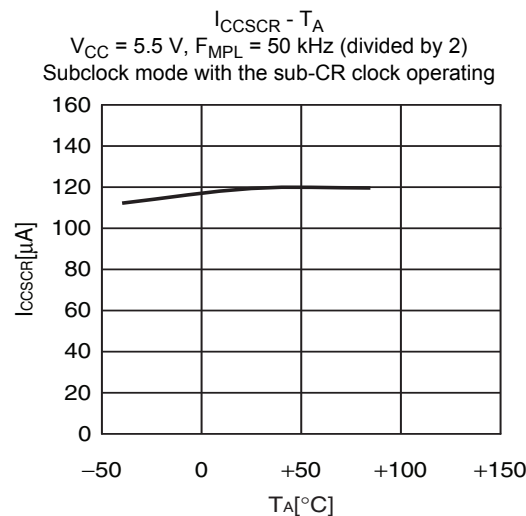
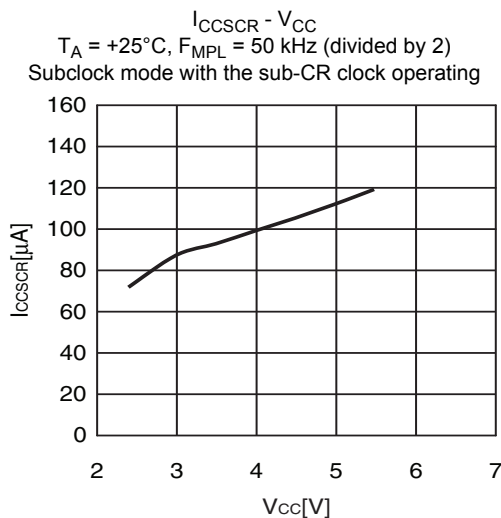
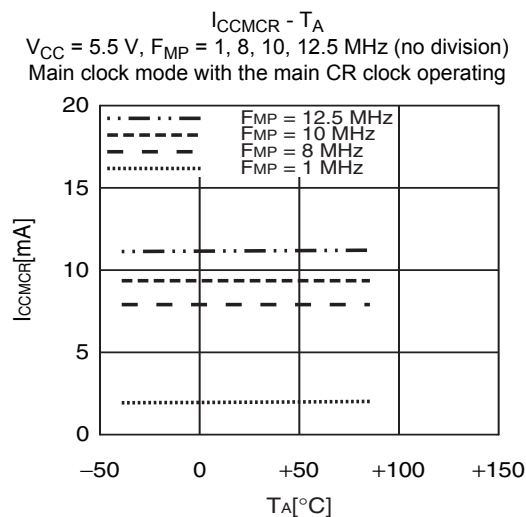
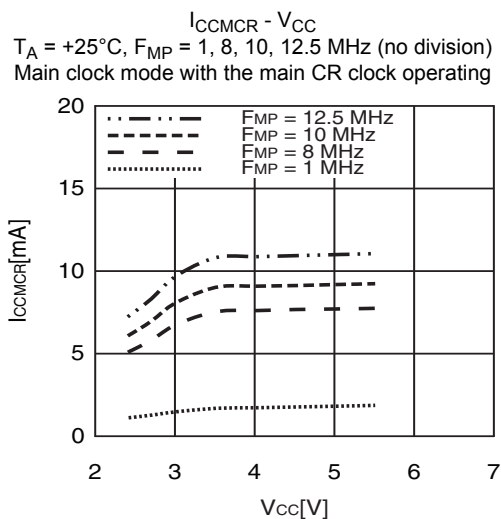
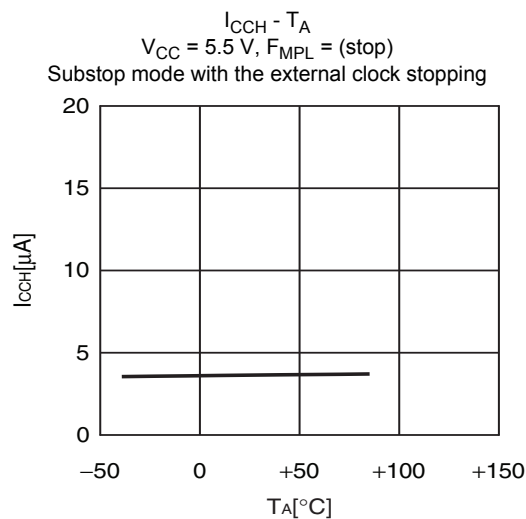
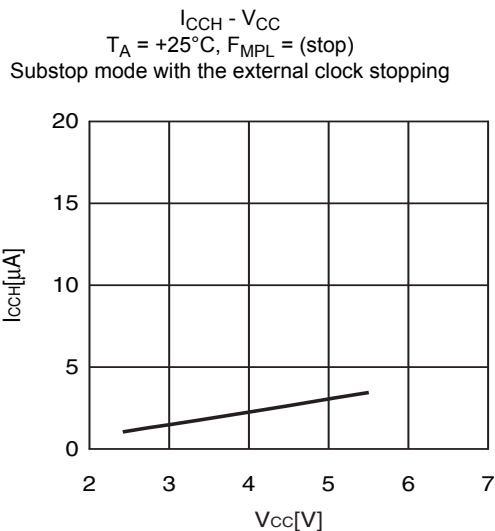
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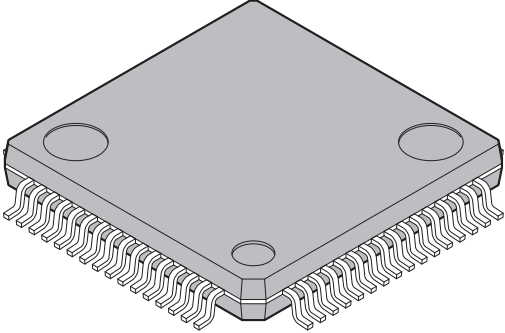
$(V_{CC} = 5.0\text{ V} \pm 10\%, AV_{SS} = V_{SS} = 0.0\text{ V}, T_A = -40^\circ\text{C to } +85^\circ\text{C})$

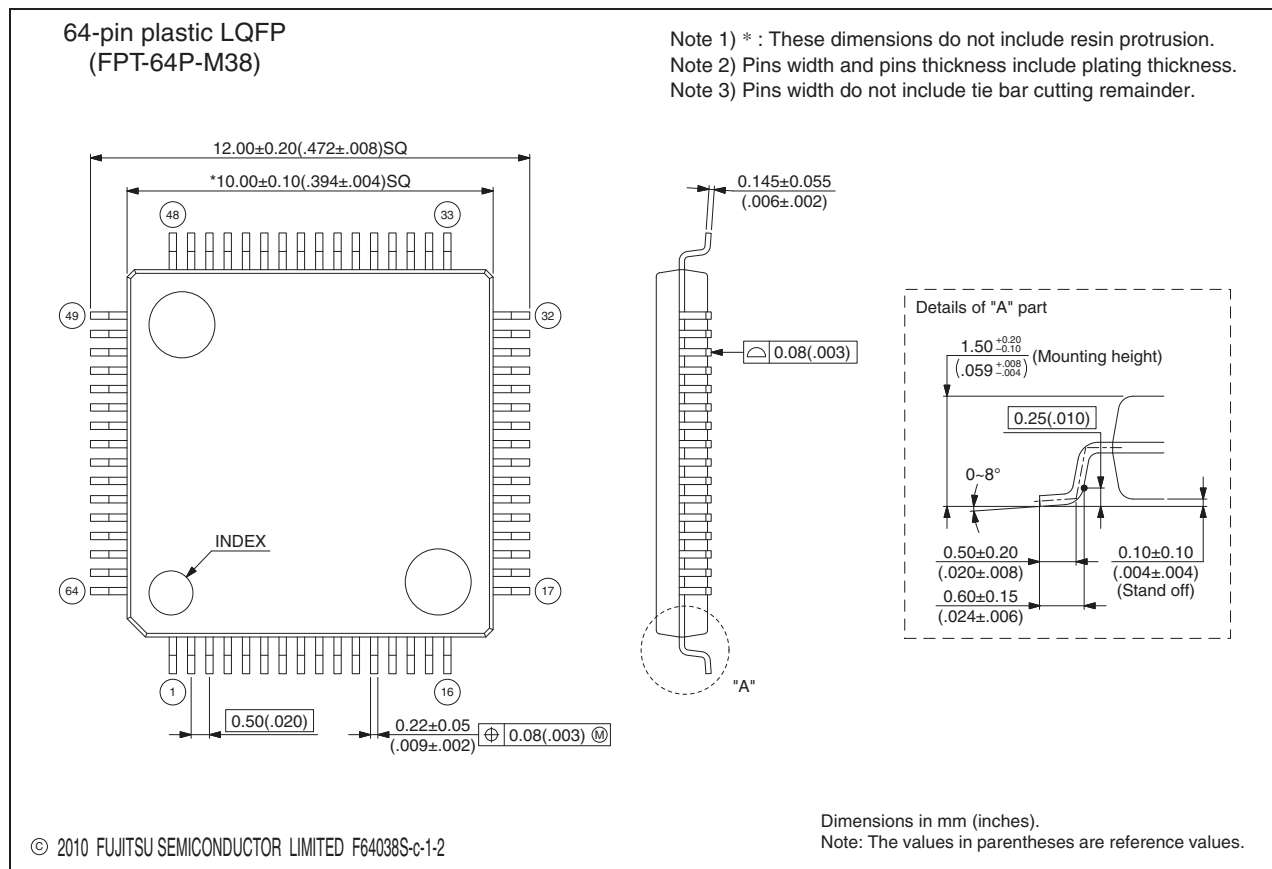
Parameter	Symbol	Pin name	Conditions	Value*2		Unit	Remarks
				Min	Max		
SCL clock "L" width	t_{LOW}	SCL	R = 1.7 k Ω , C = 50 pF*1	$(2 + nm / 2)t_{MCLK} - 20$	—	ns	Master mode
SCL clock "H" width	t_{HIGH}	SCL		$(nm / 2)t_{MCLK} - 20$	$(nm / 2)t_{MCLK} + 20$	ns	Master mode
Start condition hold time	$t_{HD;STA}$	SCL, SDA		$(-1 + nm / 2)t_{MCLK} - 20$	$(-1 + nm)t_{MCLK} + 20$	ns	Master mode Maximum value is applied when m, n = 1, 8. Otherwise, the minimum value is applied.
Stop condition setup time	$t_{SU;STO}$	SCL, SDA		$(1 + nm / 2)t_{MCLK} - 20$	$(1 + nm / 2)t_{MCLK} + 20$	ns	Master mode
Start condition setup time	$t_{SU;STA}$	SCL, SDA		$(1 + nm / 2)t_{MCLK} - 20$	$(1 + nm / 2)t_{MCLK} + 20$	ns	Master mode
Bus free time between stop condition and start condition	t_{BUF}	SCL, SDA		$(2nm + 4)t_{MCLK} - 20$	—	ns	
Data hold time	$t_{HD;DAT}$	SCL, SDA		$3 t_{MCLK} - 20$	—	ns	Master mode
Data setup time	$t_{SU;DAT}$	SCL, SDA		$(-2 + nm / 2)t_{MCLK} - 20$	$(-1 + nm / 2)t_{MCLK} + 20$	ns	Master mode When assuming that "L" of SCL is not extended, the minimum value is applied to first bit of continuous data. Otherwise, the maximum value is applied.
Setup time between clearing interrupt and SCL rising	$t_{SU;INT}$	SCL		$(nm / 2)t_{MCLK} - 20$	$(1 + nm / 2)t_{MCLK} + 20$	ns	Minimum value is applied to interrupt at 9th SCL \downarrow . Maximum value is applied to interrupt at 8th SCL \downarrow .
SCL clock "L" width	t_{LOW}	SCL		$4 t_{MCLK} - 20$	—	ns	At reception
SCL clock "H" width	t_{HIGH}	SCL		$4 t_{MCLK} - 20$	—	ns	At reception

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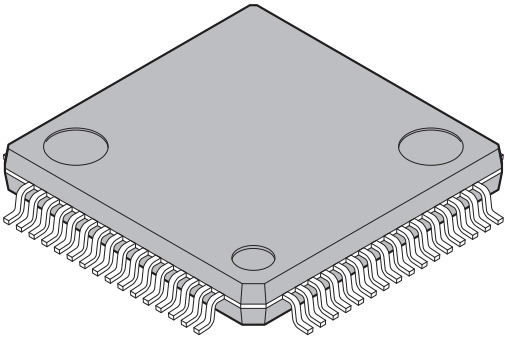


<p>64-pin plastic LQFP</p>  <p>(FPT-64P-M38)</p>	Lead pitch	0.50 mm
	Package width × package length	10.00 mm × 10.00 mm
	Lead shape	Gullwing
	Lead bend direction	Normal bend
	Sealing method	Plastic mold
	Mounting height	1.70 mm MAX
	Weight	0.32 g



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<p>64-pin plastic LQFP</p>  <p>(FPT-64P-M39)</p>	Lead pitch	0.65 mm
	Package width × package length	12.00 mm × 12.00 mm
	Lead shape	Gullwing
	Sealing method	Plastic mold
	Mounting height	1.70 mm MAX
	Weight	0.47 g

